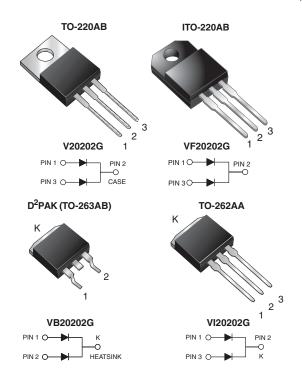


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Vishay General Semiconductor

Dual High Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.61 \text{ V}$ at $I_F = 5 \text{ A}$



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 10 A					
V _{RRM}	200 V					
I _{FSM}	130 A					
V_F at $I_F = 10$ A $(T_A = 125 ^{\circ}C)$	0.71 V					
T _J max.	175 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- Trench MOS Schottky technology Gen 2
- Low forward voltage drop, low power losses

• High efficiency operation

RoHS
COMPLIANT
HALOGEN
FREE

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D^2PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER			V20202G	VF20202G	VB20202G	VI20202G	UNIT	
Maximum repetitive peak reverse voltage			200				V	
Maximum average forward rectified current (fig. 1)	per device			20			^	
	per diode	I _{F(AV)}	10			Α		
Maximum DC reverse voltage		V_{DC}	160			V		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	130			Α		
Voltage rate of change (rated V _R)		dV/dt	10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink, t = 1 min		V _{AC}	1500			V		
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +175			°C		



V20202G, VF20202G, VB20202G, VI20202G

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)									
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT			
Instantaneous forward voltage per diode (1)	I _F = 5 A	T 05 %0		0.76	-				
	$I_F = 10 \text{ A}$ $T_A = 25 \text{ °C}$	V	0.84	0.92	v				
	I _F = 5 A	T _A = 125 °C	V _F	0.61	-	V			
	I _F = 10 A			0.71	0.8				
Reverse current per diode (2)	V _R = 160 V	T _A = 25 °C	I _R	0.3	-	μA			
	V _R = 100 V	T _A = 125 °C		0.5	-	mA			
	$V_{\rm P} = 200 \text{ V}$	T _A = 25 °C		-	150	μA			
		T _A = 125 °C		1.5	8	mA			

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	V20202G	VF20202G	VB20202G	VI20202G	UNIT	
Typical thermal resistance	per diode	$R_{ heta JC}$	2.8	5.0	2.	8		
	per device	$R_{ heta JC}$	1.6	3.5	1.	6	°C/W	
	per device	R _{0JA} (1)(2)	52	60	5	2		

Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

(2) Free air, without heatsink

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V20202G-M3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF20202G-M3/4W	1.75	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VB20202G-M3/4W	1.39	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VB20202G-M3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI20202G-M3/4W	1.45	4W	50/tube	Tube			



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

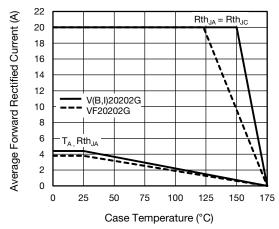


Fig. 1 - Maximum Forward Current Derating Curve (D = Duty Cycle = 0.5)

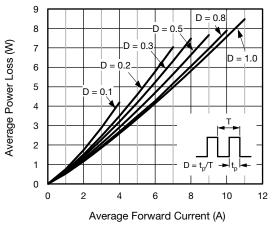


Fig. 2 - Forward Power Loss Characteristics Per Diode

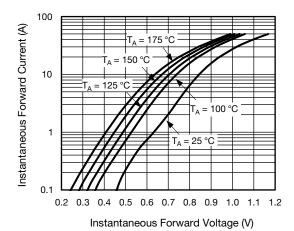


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

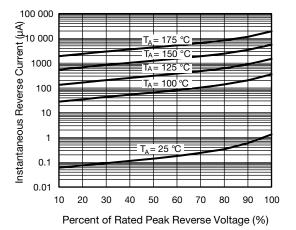


Fig. 4 - Typical Reverse Characteristics Per Diode

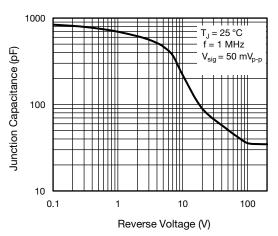


Fig. 5 - Typical Junction Capacitance Per Diode

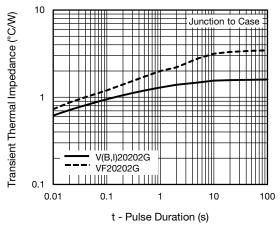


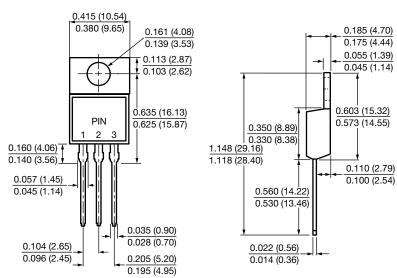
Fig. 6 - Typical Transient Thermal Impedance Per Device

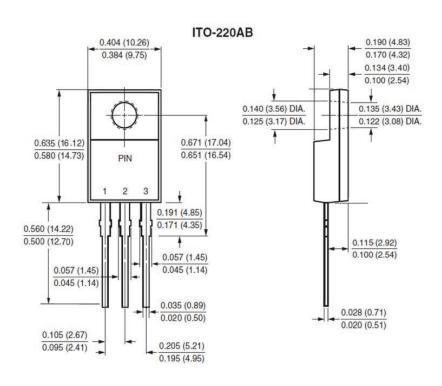


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB

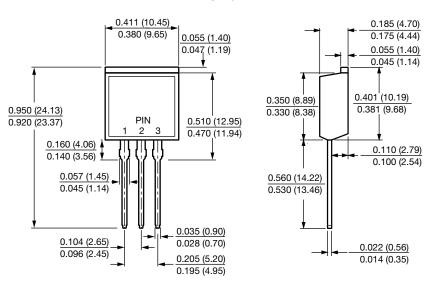




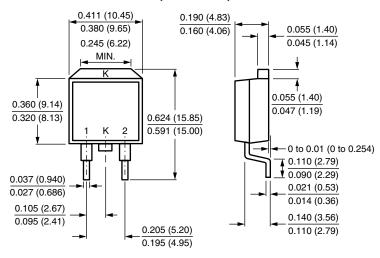


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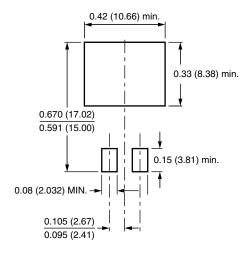
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout





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